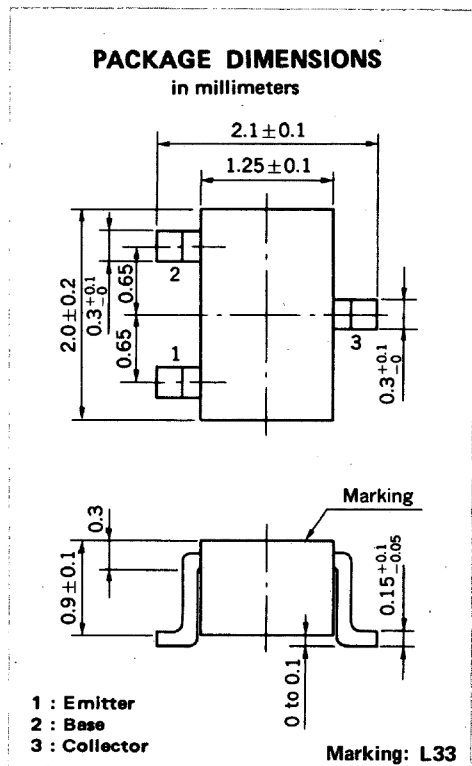


SILICON TRANSISTOR

GA1F4M

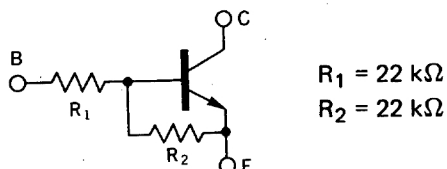
MEDIUM SPEED SWITCHING

RESISTOR BUILT-IN TYPE NPN TRANSISTOR



FEATURES

- Resistors Built-in TYPE



- Complementary to GN1F4M

ABSOLUTE MAXIMUM RATINGS

Maximum Voltages and Currents ($T_a = 25^\circ\text{C}$)

Collector to Base Voltage	V_{CBO}	60	V
Collector to Emitter Voltage	V_{CEO}	50	V
Emitter to Base Voltage	V_{EBO}	10	V
Collector Current (DC)	I_C	100	mA
Collector Current (Pulse)	I_C	200	mA

Maximum Power Dissipation

Total Power Dissipation at 25°C Ambient Temperature	P_T	150	mW
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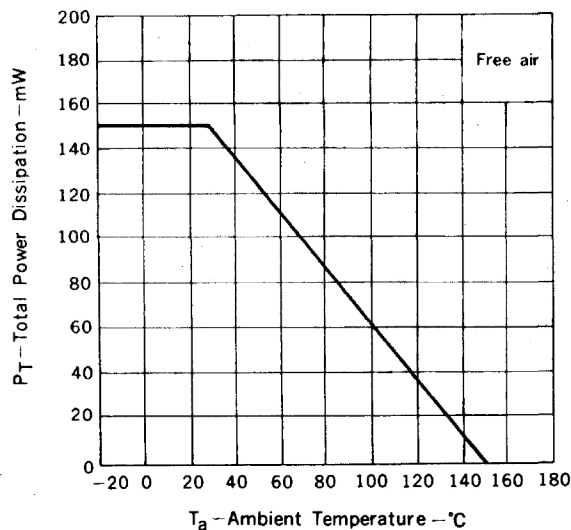
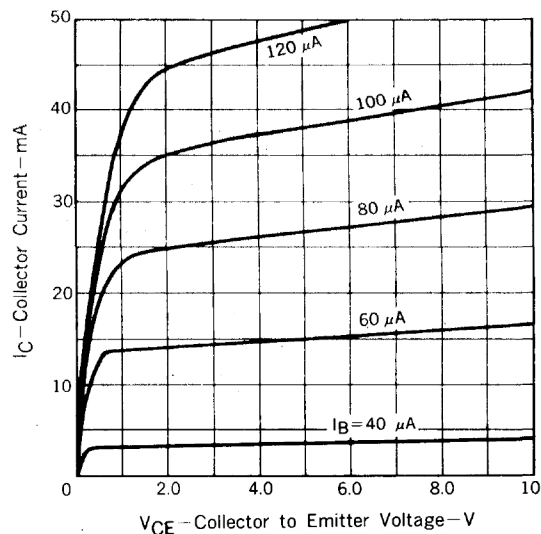
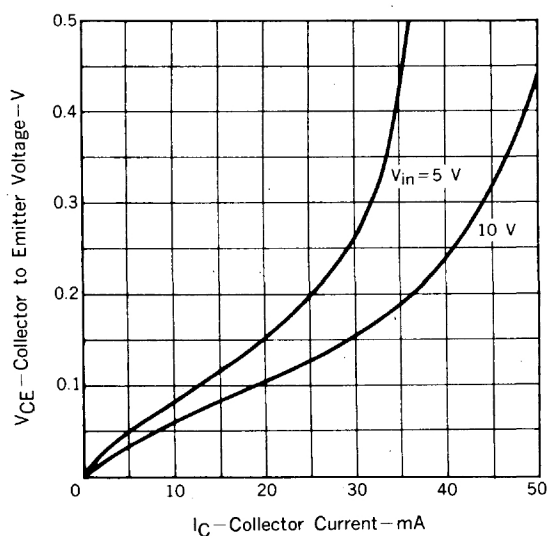
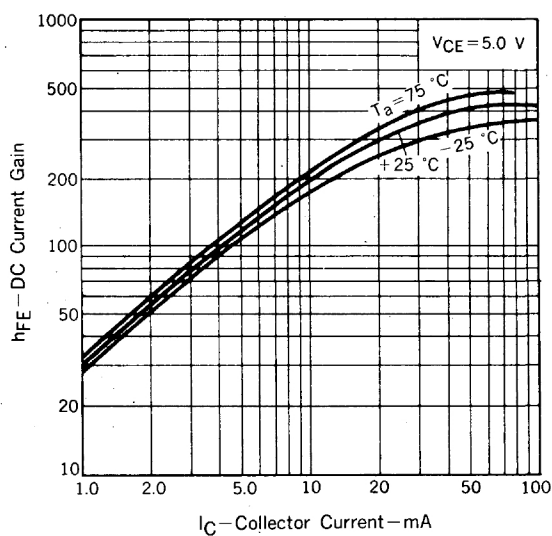
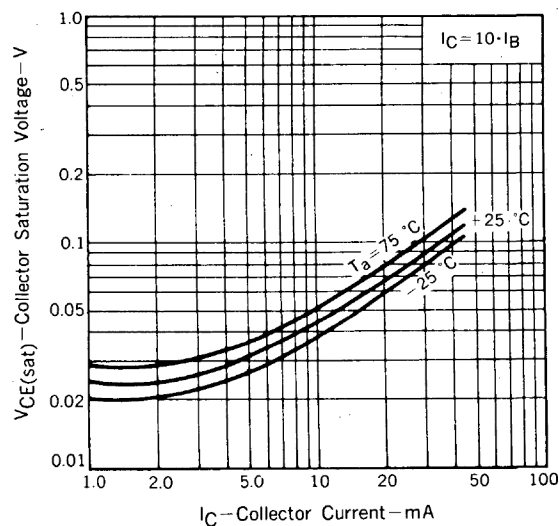
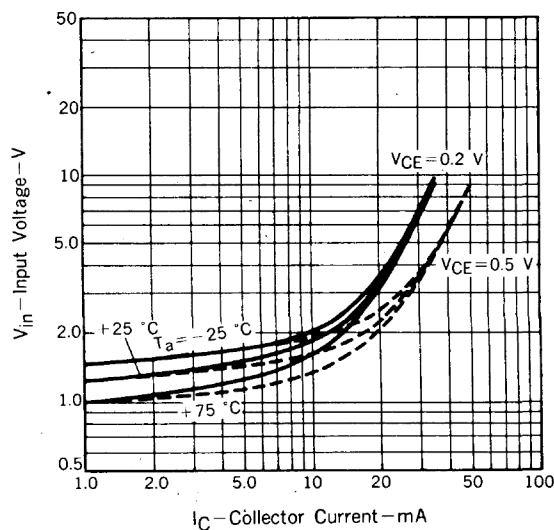
Maximum Temperatures

Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150	$^\circ\text{C}$

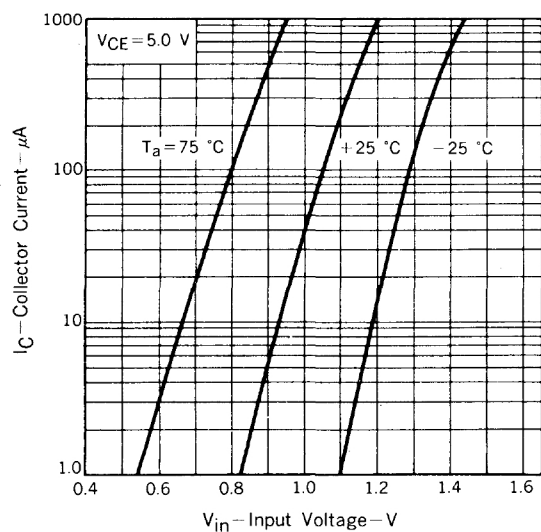
ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector Cutoff Current	I_{CBO}			100	nA	$V_{CB} = 50 \text{ V}, I_E = 0$
DC Current Gain	h_{FE1}^*	60	120	195		$V_{CE} = 5.0 \text{ V}, I_C = 5.0 \text{ mA}$
DC Current Gain	h_{FE2}^*	90	400			$V_{CE} = 5.0 \text{ V}, I_C = 50 \text{ mA}$
Collector Saturation Voltage	$V_{CE(sat)}^*$		0.04	0.2	V	$I_C = 50 \text{ mA}, I_B = 0.25 \text{ mA}$
Low-Level Input Voltage	V_{IL}^*		1.05	0.8	V	$V_{CE} = 5.0 \text{ V}, I_C = 100 \mu\text{A}$
High-Level Input Voltage	V_{IH}^*	4.0	1.6		V	$V_{CE} = 0.2 \text{ V}, I_C = 5.0 \text{ mA}$
Input Resistor	R_1	15.4	22.0	28.6	k Ω	
Resistor Ratio	R_1/R_2	0.9	1.0	1.1		
Turn-on Time	t_{on}		0.11	0.4	μs	$V_{CC} = 5 \text{ V}, V_{in} = 5 \text{ V}$ $R_L = 1 \text{ k}\Omega$ $PW = 2 \mu\text{s}, \text{Duty Cycle} \leq 2\%$
Storage Time	t_{stg}		2.3	5.0	μs	
Turn-off Time	t_{off}		2.6	6.0	μs	

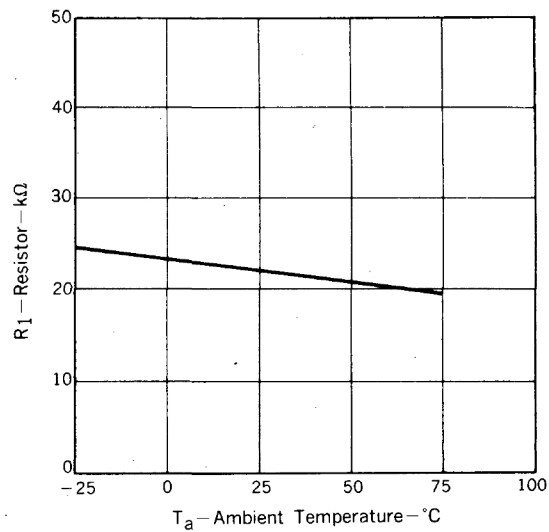
* Pulsed: $PW \leq 350 \mu\text{s}$, Duty Cycle $\leq 2\%$

TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)TOTAL POWER DISSIPATION vs.
AMBIENT TEMPERATURECOLLECTOR CURRENT vs.
COLLECTOR TO EMITTER VOLTAGECOLLECTOR TO EMITTER VOLTAGE vs.
COLLECTOR CURRENTDC CURRENT GAIN vs.
COLLECTOR CURRENTCOLLECTOR SATURATION VOLTAGE vs.
COLLECTOR CURRENTINPUT VOLTAGE vs.
COLLECTOR CURRENT

COLLECTOR CURRENT vs.
INPUT VOLTAGE



RESISTOR vs.
AMBIENT TEMPERATURE



SWITCHING TIME vs.
COLLECTOR CURRENT

